

Supporting Information

MXene-Integrated Ni–Co Telluride Composites as Restacking-Free Electrodes for Boosted Pseudocapacitive Performance

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Characterization techniques

X-ray diffraction (XRD) pattern analysis was performed for the prepared materials using Shimadzu XRD-6000, Japan with Cu K α ($\lambda = 1.5416 \text{ \AA}$) radiation at the scanning limit of $2\theta = 10^\circ$ to 90° and a scanning speed of $10^\circ \text{ min}^{-1}$. The FT-IR spectrometer (FTIR, Bruker, TENSOR 27 spectrometer) was used to gather the vibrational frequencies of the prepared NiCoTe₂/MXene composite. The Brunauer-Emmett-Teller (BET) (Micro-Trac BELCORP, Japan) analyzer was used to evaluate the specific surface area and the Barrett-Joyner-Halenda (BJH) framework was used to investigate the pore volume distributions of the prepared materials. Field Emission Scanning Electron Microscopy (FESEM) (FEI quanta 250-FESEM, Bruker, Germany) with EDAX mapping analysis predicted the surface morphology and chemical composition of the as-prepared samples. A high-resolution transmission electron microscope (HR-TEM) (JEOL JEM 2100) was used to infer the structural characterization of the synthesized materials. X-ray photoelectron spectroscopy (XPS, ESCALAB 250XI, Germany) was used to understand the valence states of the elements in the prepared NiCoTe₂/MXene composite. The electrochemical workstation (Autolab PGSTAT302N, Netherlands) was used to study the electrochemical properties and energy storage performance of the developed composites.

Specific capacity calculation

The specific capacity (Q , in the unit of mAh g^{-1}) was calculated from the integral area of the CVs curves based on the following eqn. (S1).¹

$$Q = \frac{\int Idv}{2 \times 3.6 \times m \times V} \dots\dots\dots (S1)$$

The specific capacity (Q , in the unit of mAh g^{-1}) was also calculated from the GCD discharge curves based on the following eqn. (S2).²

$$Q = \frac{I \times \Delta t}{m} / 3.6 \dots\dots\dots (S2)$$

Where 'I' is the current, Δt is the discharge time, U is the testing voltage range, and m is the mass of the active material.

Specific energy and specific power calculation

The specific energy (E) (Wh kg^{-1}) and specific power (P) (W kg^{-1}) of the composites were calculated based on the following eqns. (S3 & S4).

$$E = \left(\frac{1}{m} \int_0^{t_d} iV dt \right) \dots\dots\dots (S3)^3$$

$$P = 3600 \times \frac{E}{t_d} \dots\dots\dots (S4)^3$$

Where m is the total mass of the device, i is the discharge current, V is the potential, and t_d is the discharge time.

Charge balance calculation

Charge balance of electrodes in asymmetric supercapacitors

The charge must be balanced in an asymmetric supercapacitor device using the relationship $Q_+ = Q_-$ where Q_+ is the charge stored at the positive and Q_- is the charge stored at the

negative electrodes. The charge storage by each electrode depends on the specific capacity (Q), the potential range for the charge/discharge process (ΔE), and the mass loading of the active material (m).⁴

Coulombic efficiency calculation

The coulombic efficiency was calculated by using the following eqn. (S5).⁵

$$\eta(\%) = \frac{t_d}{t_c} \times 100 \quad \dots\dots\dots (S5)$$

Where η (%) is Coulombic efficiency, t_d (s) represents discharging time, and t_c (s) represented charging time.

Capacity retention calculation

The capacity retention was calculated by using the following eqn. (S6).⁵

$$C_R(\%) = \frac{C_F}{C_I} \times 100 \quad \dots\dots\dots (S6)$$

Where C_R (%) is capacity retention, C_F represents the final capacity, and C_I is the initial capacity.

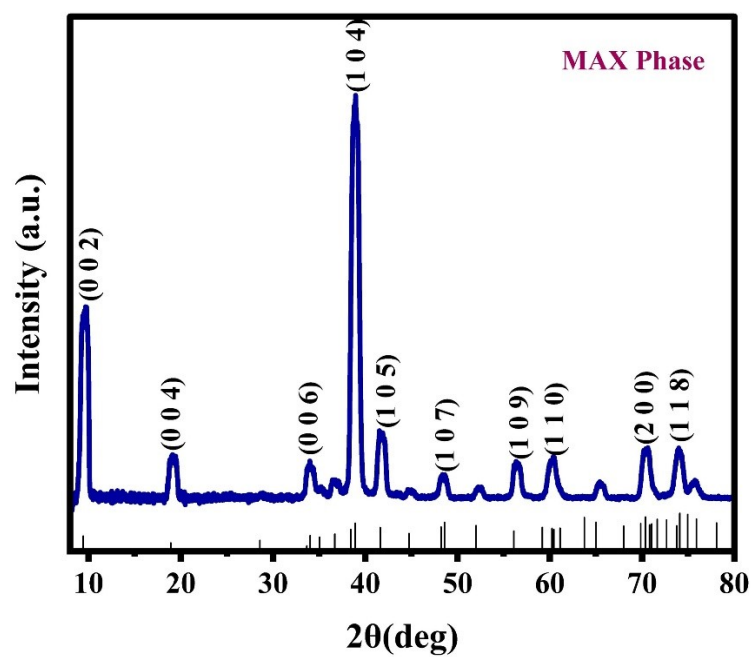


Fig. S1 XRD pattern of Ti_3AlC_2 MAX phase.

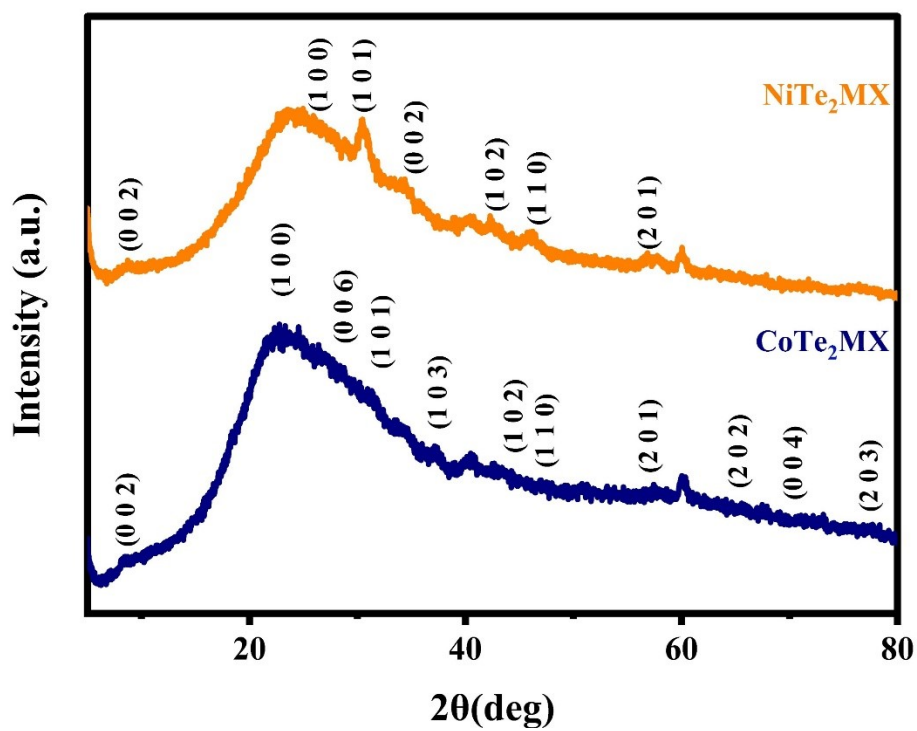


Fig. S2 XRD patterns of NiTe_2MX and CoTe_2MX composites.

Table S1: The 2θ and hkl values of NiCoTe₂ and MXene derived from XRD patterns.

NiCoTe ₂	
2θ	hkl values
26.436°	(1 0 0)
31.295°	(1 0 1)
33.373°	(0 0 2)
42.904°	(1 0 2)
53.86°	(2 0 0)
58.282°	(1 0 3)
70.084°	(0 0 4)
74.376°	(2 1 0)
12.74°	(0 2 1)
19.75°	(0 0 1)
21.11°	(1 1 1)
27.90°	(1 0 0)
MXene	
9.436°	(0 0 2)
18.937°	(0 0 4)
28.572°	(0 0 6)

18.93°	(0 1 9)
36.689°	(1 0 3)
38.418°	(0 0 8)
54.29°	(1 0 8)
56.06°	(1 0 9)
67.962°	(1 1 6)

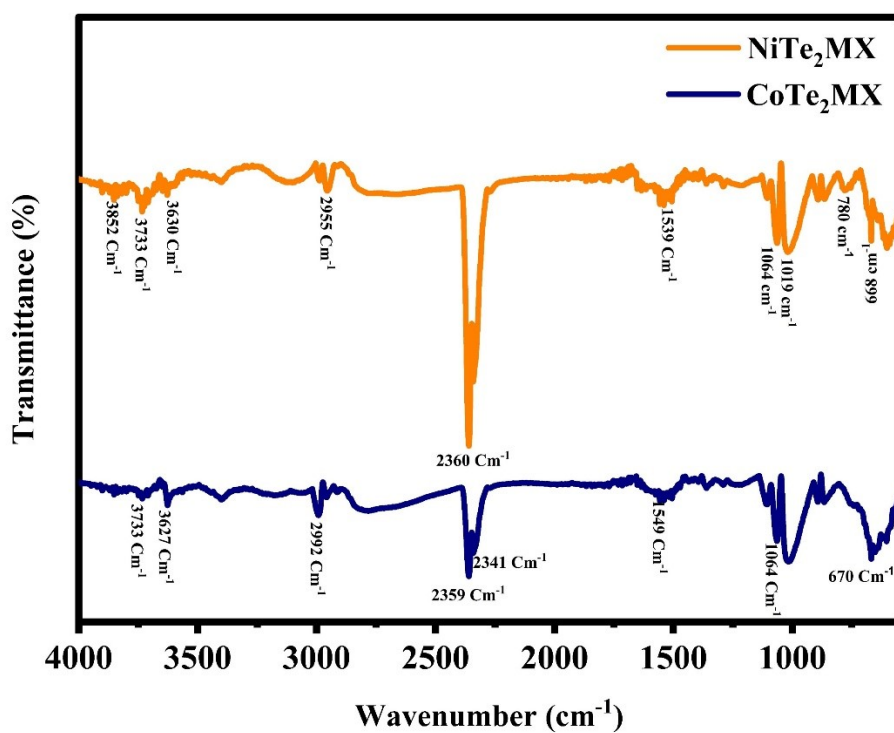


Fig. S3 FTIR spectra of NiTe₂MX and CoTe₂MX composites.

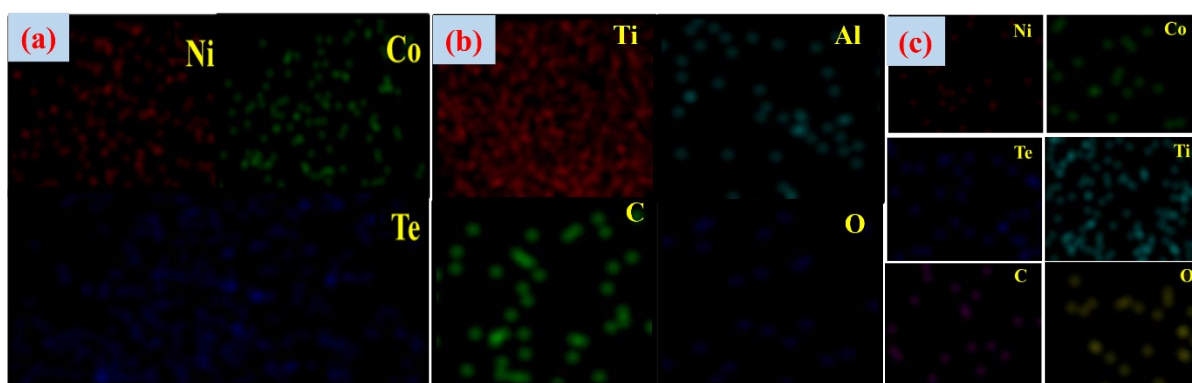


Fig. S4 Elemental mapping of (a) NiCoTe₂, (b) MXene, and (c) NiCoTe₂/MXene composites.

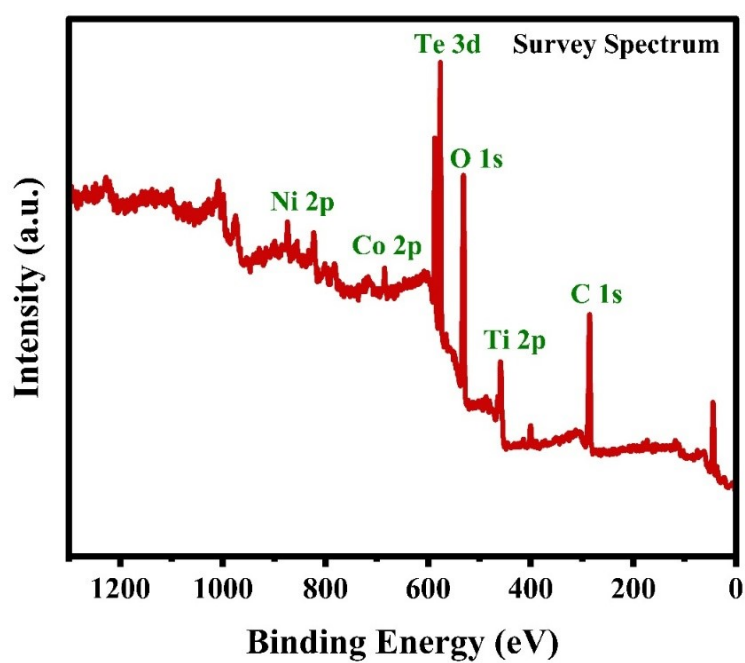


Fig. S5 XPS survey spectrum of NiCoTe₂/MXene composites.

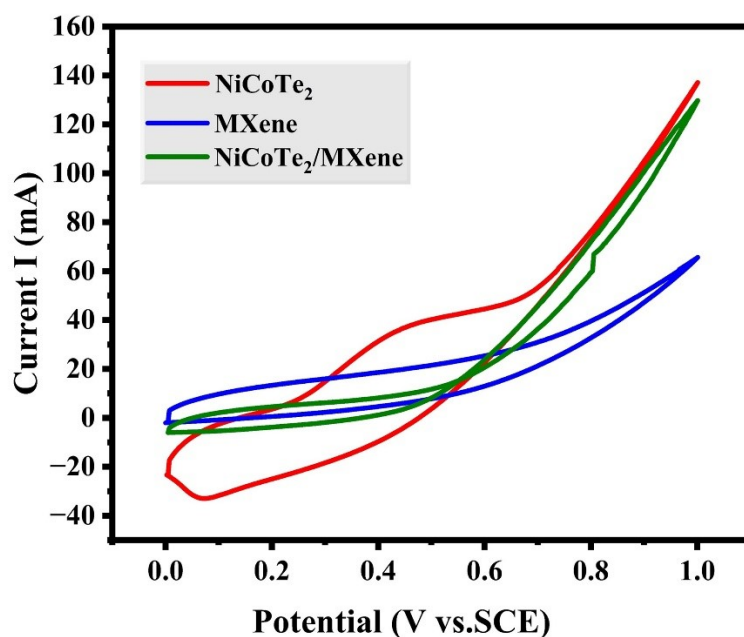


Fig. S6 CVs recorded in the positive window for NiCoTe₂, MXene, and NiCoTe₂/MXene composite in 6.0 M KOH.

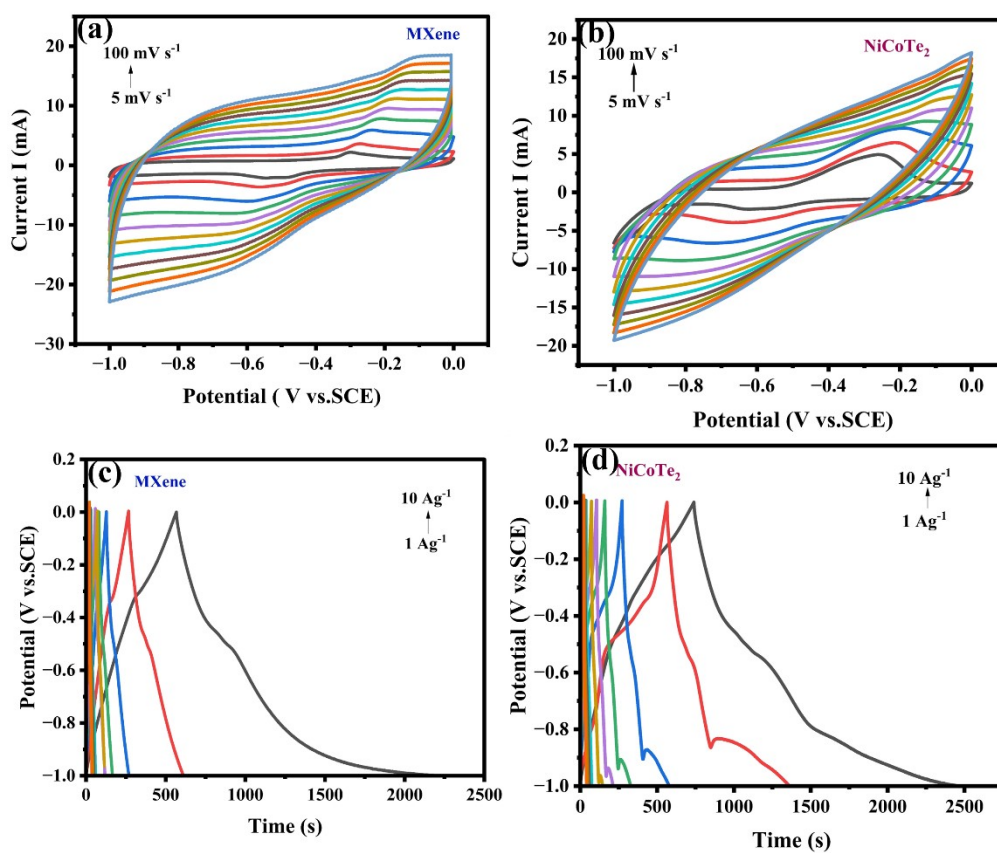


Fig. S7 CVs recorded for (a, b) MXene, NiCoTe₂ coated on GS electrodes with increasing scan rates from 5 to 100 mV s⁻¹ in 6.0 M KOH, GCD performances of MXene and NiCoTe (c, d) performed at different current densities (1-10 Ag⁻¹).

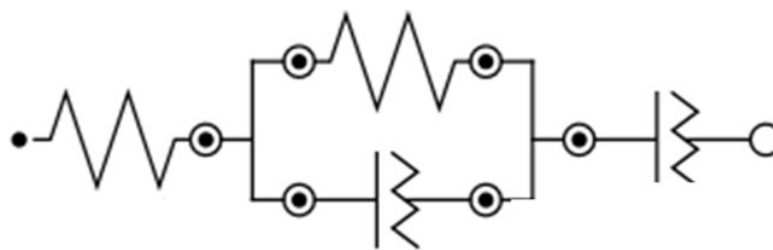


Fig. S8 Equivalent circuit fitted for NiCoTe₂/MXene composite.

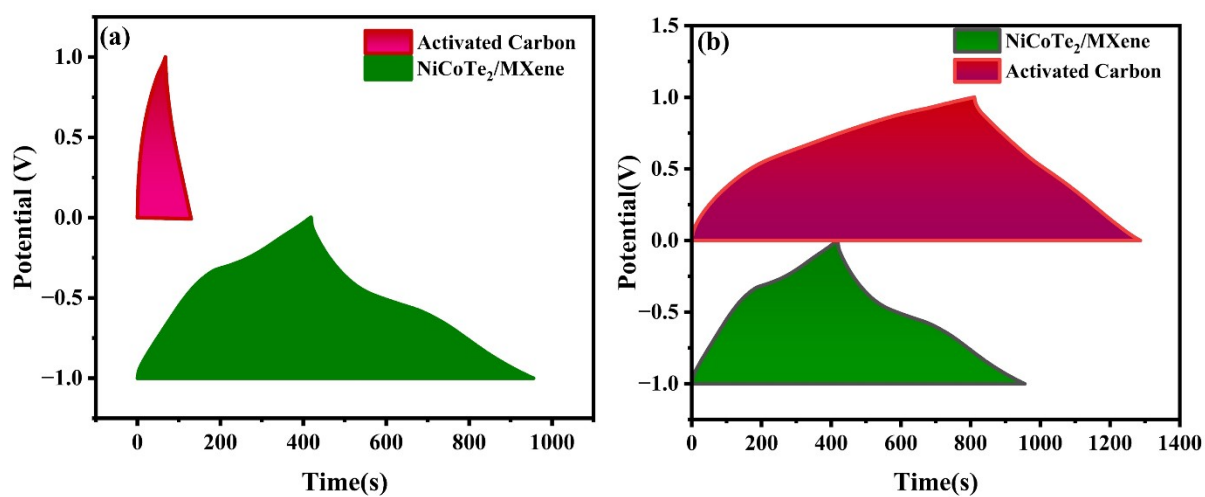


Fig. S9 Two electrode studies of NiCoTe₂/MXene||AC asymmetric supercapacitor (a-b) mass balance of GCD curves.

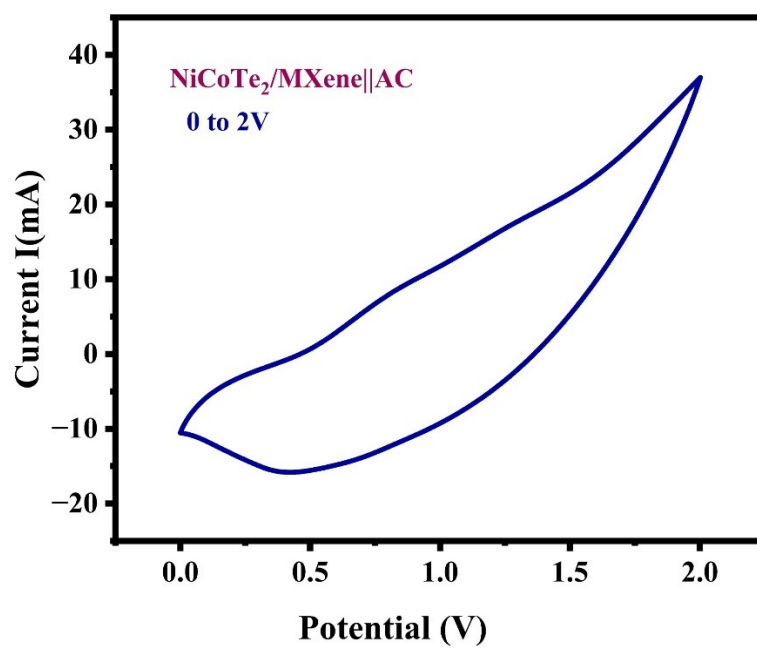


Fig. S10 CV curve of NiCoTe₂/MXene||AC electrode for the extended potential window from 0 to 2.0 V.

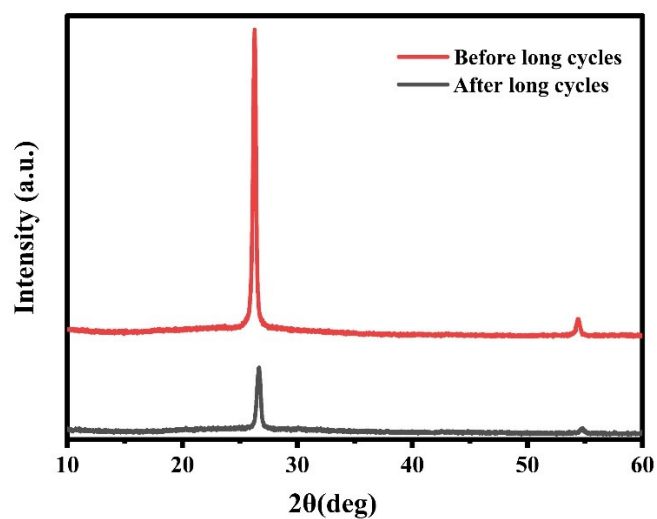


Fig. S11 Pre and post-cycled XRD patterns of NiCoTe₂/MXene composites.

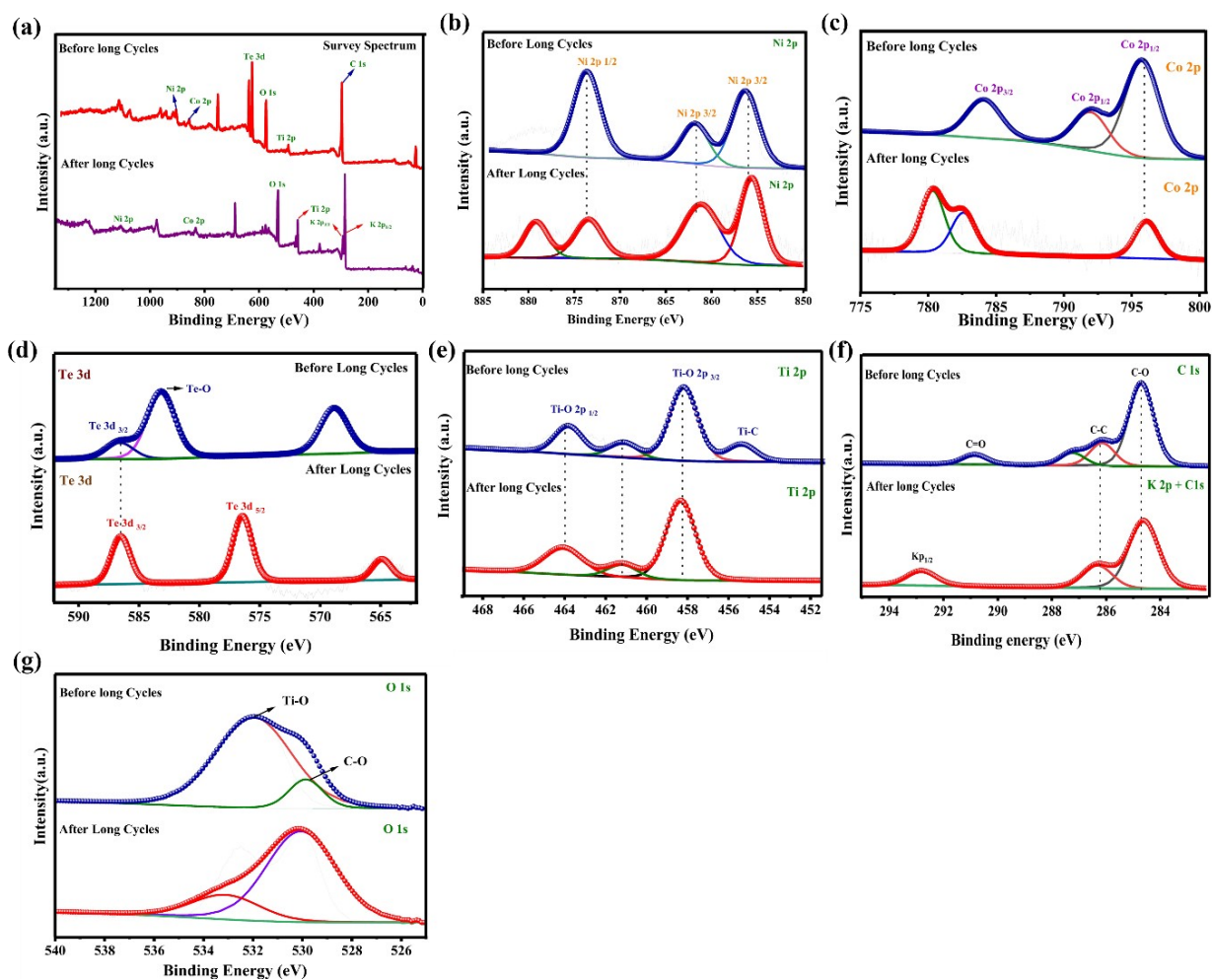


Fig. S12 Pre and post cycled XPS survey spectra of NiCoTe₂/MXene composite (a), post cycled XPS of individual element of (b) Ni 2p (c) Co 2p (d) Te 3d (e) Ti 2p (f) C 1s (g) O 1s.

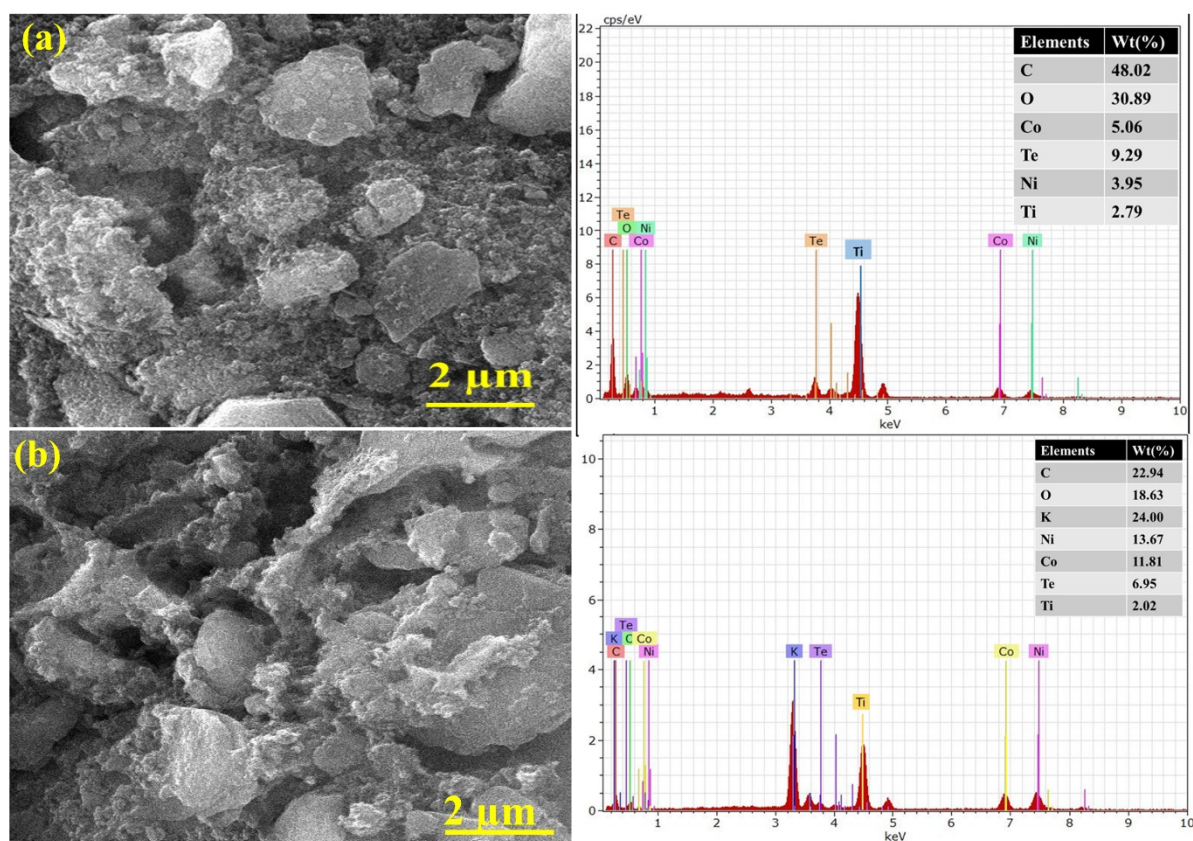


Fig. S13 SEM and EDAX images of (a) before and (b) after long cycles of NiCoTe₂/MXene composite.

Table S2. Comparison of NiCoTe₂/MXene||AC modified graphite sheet electrode concerning specific capacity, power, and energy densities to those reported elsewhere.

Electrode	Electrolyte	Specific capacitance		Power density	Energy density	Comments (Solid-state electrolyte)	Ref
		Three electrode 1 A g ⁻¹ (mAh g ⁻¹)	Two electrode 1 A g ⁻¹ (mAh g ⁻¹)				
NiSb/NiTe ^a	6.0 M	519.4	430.5	750 μW cm ⁻²	224.6 μWh cm ⁻²	Not used	⁶
CoTe@rGO ^b	3.0 M KOH	225.16	31.27	799.91 W kg ⁻¹	40.04 Wh kg ⁻¹	Not used	⁷
MCTe/NFTe@ NiF ^c	3.0 M KOH	223.36	144.98	799.98 W kg ⁻¹	51.55 Wh kg ⁻¹	Not used	⁸
NbTe ₂ @rGO ^d	2.0 M KOH	409.7	138.3	285 W kg ⁻¹	22 Wh kg ⁻¹	Not used	⁹
NiTe ₂ - Co ₂ Te ₂ @rGO ^e	1.0 M KOH	223.6	64	800 W kg ⁻¹	51 Wh kg ⁻¹	Not used	¹⁰
CoTe/Co/CoO ^f	2.0 M KOH	139.17 at 5 mA cm ⁻²	-	616.26 W kg ⁻¹	35.29 Wh kg ⁻¹	Not used	¹¹
NiTe:Co ^g	3.0 M KOH	457.1	242.4		36.8 Wh kg ⁻¹	Not used	¹²
NiLaTe ^h	2.0 M KOH	95.7	60.0	5,488.7 W kg ⁻¹	45.5 Wh kg ⁻¹	Used	¹³
NiCoTe ₂ NRs ⁱ	3.5 M KOH	120 at 0.5 A g ⁻¹	106 at 0.5 Ag ⁻¹	905 W kg ⁻¹	43 Wh kg ⁻¹	Not used	¹⁴
Te NTs@CoMgTe MTs) ^j	2.0 M KOH	42.4	56.3	6,857.1 W kg ⁻¹	42.2 Wh kg ⁻¹	Used	¹⁵
Co-Fe decorated	4.0 M KOH	1,119.2	179.2	1,138.2	62.1	Not used	¹⁶

Te ^k				W kg ⁻¹	Wh kg ⁻¹		
Co-decorated Te nanotubes	4.0 M KOH	77	40.83	2,294 W kg ⁻¹	51.1 Wh kg ⁻¹	Not used	¹⁷
CF@CoTe ₂ -NiTe ₂ ^m	6.0 MKOH	261.4	131.1	750 W kg ⁻¹	41 Wh kg ⁻¹	Not used	¹⁸
CoTe ₂ /ZnTe/Ti ₃ C ₂ T _x ⁿ	4.0 M KFSI in dimethoxyethane	137.0 at 10 Ag ⁻¹	175.3 at 10 Ag ⁻¹	837.2 W kg ⁻¹	220.2 Wh kg ⁻¹	Not used	¹⁹
V ₂ CT _x @CoMn ₂ O ₄ ^o	1.0 M H ₂ SO ₄	158.3	47.2	440 W kg ⁻¹	62 Wh kg ⁻¹	Not used	²⁰
Mo ₂ CT _x /Ni, Co-MOF ^p	1.0 M KOH	16.1	-	293 W kg ⁻¹	22 Wh kg ⁻¹	Used	²¹
NiCoTe ₂ /MXene AC	6.0 M KOH	582	298	11,520 W kg ⁻¹	233 Wh kg ⁻¹	Used & discussed	This Work

^aNiSb/NiTe/Ni -nickel antimony/nickel telluride on nickel foam. ^bCoTe@reduced graphene oxide. ^cMnCoTe/NiFeTe on a NiF. ^dFabrication of rGO with niobium telluride (NbTe₂). ^eSpherical NiTe₂-Co₂Te₂ grown on the rGO. ^fCo(OH)₂ nanosheet transformed into CoTe, metallic Co, and CoO composite. ^gNiTe: Co nanoparticles supported on nickel foam. ^hThe NiTe MFs and La₂Te₃ microrods (MRs). ⁱnickel cobalt telluride nanorods. ^jtellurium nanotubes, cobalt magnesium telluride microtubes. ^kCobalt-iron (CoFe) decorated tellurium nanotubes. ^lCo-decorated Te nanotubes. ^mnickel-cobalt telluride. ⁿCobalt telluride/zinc telluride (CoTe₂/ZnTe) onto MXene nanosheets. ^oV₂C@CoMn₂O₄ Vanadium carbide MXene on cobalt manganese oxide. ^pNi, Co bimetallic metal-organic frameworks (Ni, Co-MOF) on Mo₂CT_xMXene.

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